

High-performance Randomized Matrix Computations for Big Data Analytics and Applications



● Background

- Developing random sketching algorithms with high-performance implementations on supercomputers to compute **singular value decomposition (SVD) and linear system (LS)** solutions of very large-scale matrices.
- Few numerical solvers, especially **randomized algorithms**, are designed to tackle very large-scale matrix computations on the latest supercomputers.
- We intend to develop efficient sketching schemes to compute approximate SVD and LS solutions of large-scale matrices. The main idea is to sketch the matrices by randomized algorithms **to reduce the computational dimensions and then suitably integrate the sketches** to improve the accuracy and to lower the computational costs.
- We intend to implement the proposed algorithms on supercomputers. One essential component of this project is to develop effective **automatic software auto-tuning (AT)** technologies, so that the package can fully take advantage of the computational capabilities of the target supercomputers that include CPU homogeneous and CPU-GPU heterogeneous parallel computers.

● Members

- **Takahiro Katagiri** (Nagoya U., Japan) : AT (ppOpen-AT), parallel eigenvalue algorithms, and supercomputer implementations.
- **Weichung Wang** (National Taiwan U., Taiwan): Numerical linear algebra, parallel computing, and AT (surrogate-assisted tuning). and big data applications.
- **Su-Yun Huang** (Institute of Statistical Science, Academia Sinica, Taiwan) : Mathematical statistics and machine learning (random sketching algorithm).
- **Kengo Nakajima** (U. Tokyo, Japan) : Parallel algorithms in numerical iterative method (hybrid MPI/OpenMP execution).
- **Osni Marques** (LBNL, USA) : Eigenproblem and its implementation (LAPACK, SVD algorithms).
- **Feng-Nan Hwang** (National Central U., Taiwan) : Eigenproblem and its parallelization (SLEPc, SVD algorithms)
- **Toshio Endo** (TITECH, Japan) : System software (optimizations for hierarchical memory and adaptation of its AT)
- (Collaborator) **Akihiro Ida** (U. Tokyo, Japan): Providing matrices by H-Matrix

● iSVD Algorithm

Rank-k SVD

$$A \approx U_k \Sigma_k V_k^T$$

U_k is an $m \times k$ orthonormal matrix that $k < m$, Σ_k is a $k \times k$ diagonal matrix, and V_k is an $n \times k$ orthonormal matrix. The columns of U_k and V_k are the leading left singular vectors and right singular vectors of A , respectively. The diagonal entries of Σ_k are the k largest singular values of A .

Algorithm 2 Integrated SVD with multiple sketches (iSVD).

Require: Input A (real $m \times n$ matrix), k (desired rank of approximate SVD), p (oversampling parameter), $\ell = k + p$ (dimension of the sketched column space), q (power of projection), N (number of random sketches)

Ensure: Approximate rank- k SVD of $A \approx \hat{U}_k \hat{\Sigma}_k \hat{V}_k^T$

- 1: Generate $n \times \ell$ random matrices $\Omega_{[i]}$ for $i = 1, \dots, N$
- 2: Assign $Y_{[i]} \leftarrow (AA^T)^q A \Omega_{[i]}$ for $i = 1, \dots, N$ with $\Omega_{[i]} = \Omega_{qp}$ or Ω_{es} (in parallel)
- 3: Compute $Q_{[i]}$ whose columns are orthonormal basis of $Y_{[i]}$ (in parallel)
- 4: Integrate $\bar{Q} \leftarrow \{Q_{[i]}\}_{i=1}^N$ (by Algorithm 3 or Algorithm 4)
- 5: Compute SVD of $\bar{Q}^T A = \bar{W}_\ell \bar{\Sigma}_\ell \bar{V}_\ell^T$
- 6: Assign $\hat{U}_\ell \leftarrow \bar{Q} \bar{W}_\ell$
- 7: Extract the largest k singular-pairs from $\hat{U}_\ell, \bar{\Sigma}_\ell, \bar{V}_\ell$ to obtain $\hat{U}_k, \hat{\Sigma}_k, \hat{V}_k$

(By Prof. Ida at U. Tokyo)

● Research Plan

- Year 1 (FY2016): Algorithm development and testing environments deployment. (A prototyping)
- **Year 2 (FY2017): Large-scale implementation and software integrations.**
- Year 3: Auto-tuning of large-scale codes and tests of applications.

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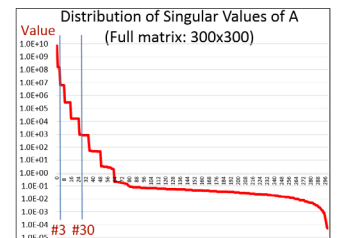
● Test Problem

Test Problem for Low Rank Approximation

- **Static electric field analysis**
- Potential operator: $V_{[p]}(x) := \int_{\Gamma} \frac{1}{4\pi|x-y|} u(y) dy, x \in \Gamma$
- Induced surface charge is calculated in half-infinite domain.

■ **Sample matrix**

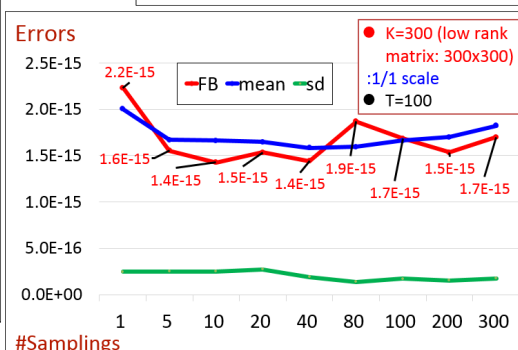
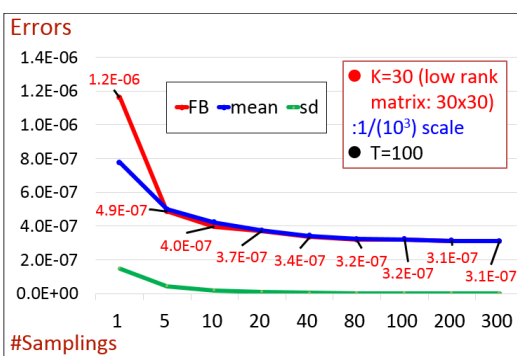
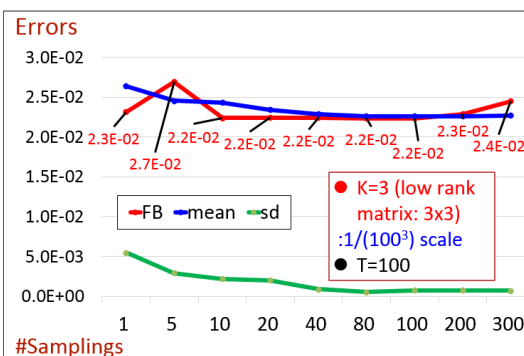
- size: $N=300 \times 300$
- Potential low-rank matrix
- Interaction between conductor & mirror image



- **Frobenius Norm (FB)**
- $\|A - U\Lambda V^T\|_F / \|A\|_F$
- **Mean**
- $\sum_{i=1}^T (\|A - U\Lambda V^T\|_F / \|A\|_F)_i / T$
- **Sqrt (sd)**
- $\sqrt{(\sum_{i=1}^T (\|A - U\Lambda V^T\|_F / \|A\|_F - \text{mean})_i)^2}$

Where T is the number of test trials of iSVD.

● Results (Accuracy of Low Rank Approximation by iSVD)



● \Rightarrow If you accept accuracy of $O(2E-02)$, computation complexity is reduced to $O(1/100^3) = O(1/1,000,000)$